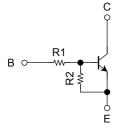
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN1907FE,RN1908FE,RN1909FE

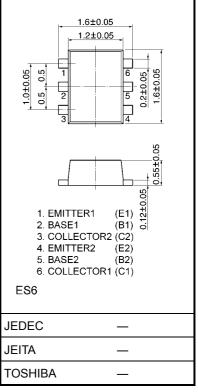
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Extreme-Super-Mini (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Complementary to RN2907FE~RN2909FE

Equivalent Circuit and Bias Resistor Values

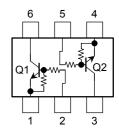


Type No.	R1 (kΩ)	R2 (kΩ)
RN1907FE	10	47
RN1908FE	22	47
RN1909FE	47	22



Weight: g (typ.)

Equivalent Circuit (top view)



Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage	RN1907FE~	V _{CBO}	50	V	
Collector-emitter voltage	RN1909FE	V _{CEO}	50	V	
	RN1907FE		6	V	
Emitter-base voltage	RN1908FE	V _{EBO}	7		
	RN1909FE		15		
Collector current		Ι _C	100	mA	
Collector power dissipation	RN1907FE~	P _C (Note)	100	mW	
Junction temperature	RN1909FE	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Total rating

Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1907FE~1909FE	I _{CBO}	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$			100	nA
		I _{CEO}	$V_{CE}=50~V,~I_B=0$			500	
	RN1907FE		$V_{EB} = 6 V, I_{C} = 0$	0.081		0.15	
Emitter cut-off current	RN1908FE	I _{EBO}	$V_{EB} = 7 V, I_{C} = 0$	0.078		0.145	mA
	RN1909FE		$V_{EB} = 15 \text{ V}, \text{ I}_{C} = 0$	0.167		0.311	
	RN1907FE			80		_	
DC current gain	RN1908FE	h _{FE}	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$	80			
	RN1909FE			70			
Collector-emitter saturation voltage	RN1907FE~1909FE	V _{CE (sat)}	$I_C = 5 \text{ mA},$ $I_B = 0.25 \text{ mA}$		0.1	0.3	V
	RN1907FE			0.7		1.8	
Input voltage (ON)	RN1908FE	V _{I (ON)}	$V_{CE}=0.2~V,~I_C=5~mA$	1.0		2.6	V
	RN1909FE			2.2	_	5.8	
	RN1907FE			0.5		1	
Input voltage (OFF)	RN1908FE	V _{I (OFF)}	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 0.1 \text{ mA}$	0.6		1.16	V
	RN1909FE			1.5		2.6	
Transition frequency	RN1907FE~1909FE	f _T	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$		250		MHz
Collector output capacitance	RN1907FE~1909FE	C _{ob}	$\begin{array}{l} V_{CB}=10 \text{ V}, \text{ I}_{E}=0, \\ f=1 \text{ MHz} \end{array}$		3	6	pF
	RN1907FE			7	10	13	
Input resistor	RN1908FE	R1	_	15.4	22	28.6	kΩ
	RN1909FE			32.9	47	61.1	
Resistor ratio	RN1907FE			0.191	0.213	0.232	
	RN1908FE	R1/R2	_	0.421	0.468	0.515	
	RN1909FE			1.92	2.14	2.35	

Type Name	Marking
RN1907FE	Type name XH
RN1908FE	Type name X1
RN1909FE	Type name

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